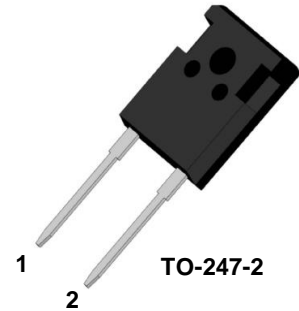


PRODUCT FEATURES

- Ultrafast Recovery Time
- Low Recovery Loss
- Soft Reverse Recovery Characteristics
- Low Leakage Current
- Low Forward Voltage
- High Surge Current Capability

APPLICATIONS

- Freewheeling, Snubber, Clamp
- Inversion Welder
- PFC
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- UPS



1-Cathode
2-Anode

DESCRIPTION

FRED from MacMic utilizes advanced processing techniques to achieve ultrafast recovery times and higher forward current. Its soft recovery characteristics and high reliability suit for wide industrial applications.

ABSOLUTE MAXIMUM RATINGS ($T_C=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter/Test Conditions		Values	Unit
V_R	Maximum D.C. Reverse Voltage		600	V
V_{RRM}	Maximum Repetitive Reverse Voltage			
$I_{F(AV)}$	Average Forward Current	$T_C=115^\circ\text{C}$	100	A
$I_{F(RMS)}$	RMS Forward Current	$T_C=115^\circ\text{C}$	140	
I_{FSM}	Non Repetitive Surge Forward Current	$T_J=25^\circ\text{C}, t=10\text{ms}, 50\text{Hz}, \text{Sine}$	900	
P_D	Power Dissipation		577	W
T_J	Junction Temperature		-65 to +175	$^\circ\text{C}$
T_{STG}	Storage Temperature Range		-65 to +150	$^\circ\text{C}$
Torque	To Heat Sink	Recommended (M3)	1.1	Nm
R_{thJC}	Junction to Case Thermal Resistance		0.26	$^\circ\text{C}/\text{W}$
Weight			6	g

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter/Test Conditions		Min.	Typ.	Max.	Unit
I_{RM}	Maximum Reverse Leakage Current	$V_R=600\text{V}$			10	μA
		$V_R=600\text{V}, T_J=125^\circ\text{C}$			1	mA
V_F	Forward Voltage	$I_F=100\text{A}$		1.55	2.00	V
		$I_F=100\text{A}, T_J=125^\circ\text{C}$		1.30		

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MM100F60B

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter/Test Conditions	Min.	Typ.	Max.	Unit
t_{rr}	Reverse Recovery Time		100		ns
I_{RRM}	Maximum Reverse Recovery Current		8		A
Q_{RR}	Reverse Recovery Charge		300		nC
t_{rr}	Reverse Recovery Time		160		ns
I_{RRM}	Maximum Reverse Recovery Current		13		A
Q_{RR}	Reverse Recovery Charge		1100		nC
t_{rr}	Reverse Recovery Time		95		ns
I_{RRM}	Maximum Reverse Recovery Current		45		A
Q_{RR}	Reverse Recovery Charge		2000		nC

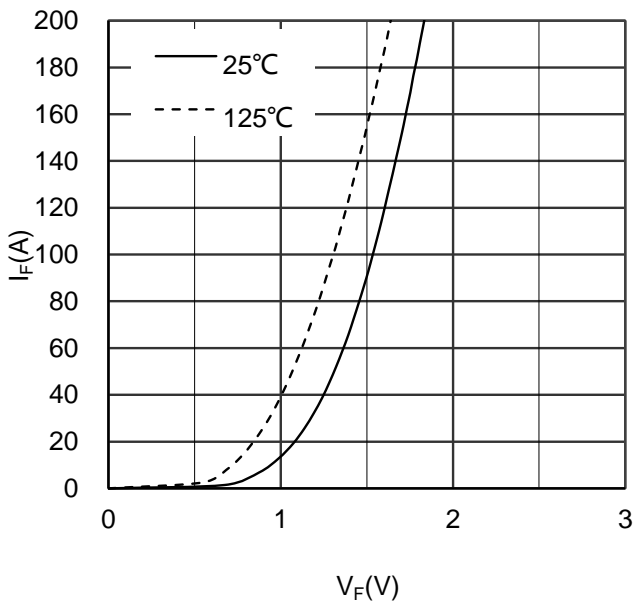


Figure 1. Forward Voltage Drop vs Forward Current

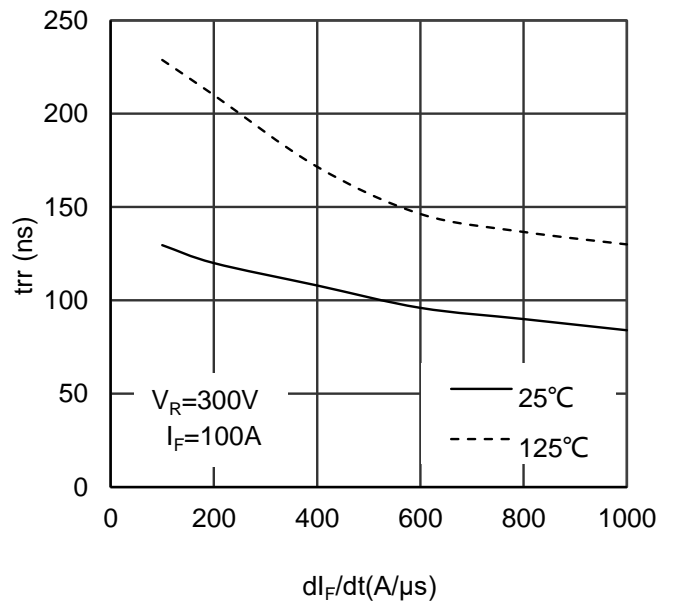


Figure 2. Reverse Recovery Time vs di_F/dt

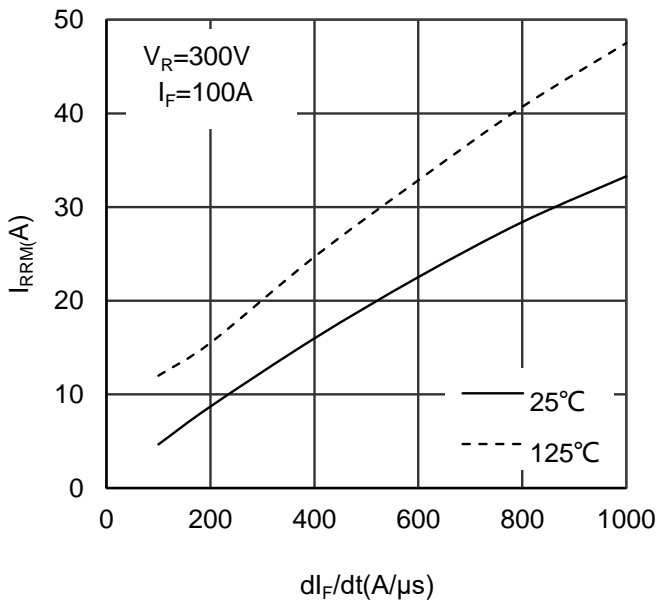


Figure 3. Reverse Recovery Current vs di_F/dt

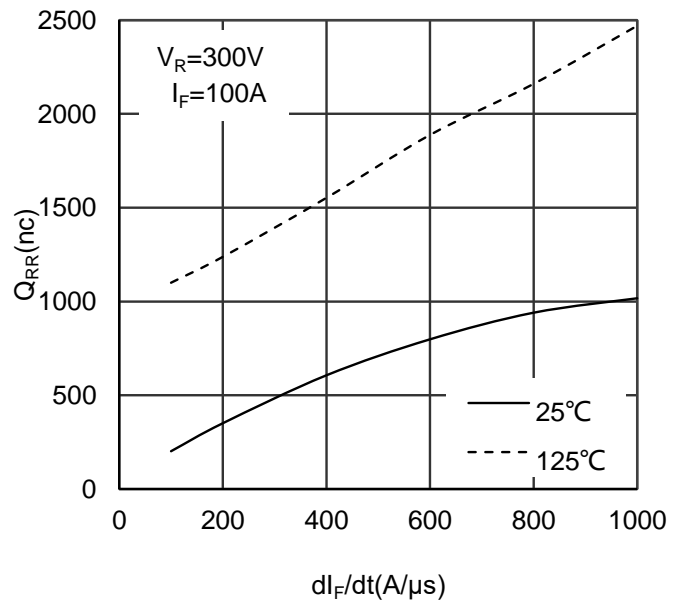


Figure 4. Reverse Recovery Charge vs di_F/dt

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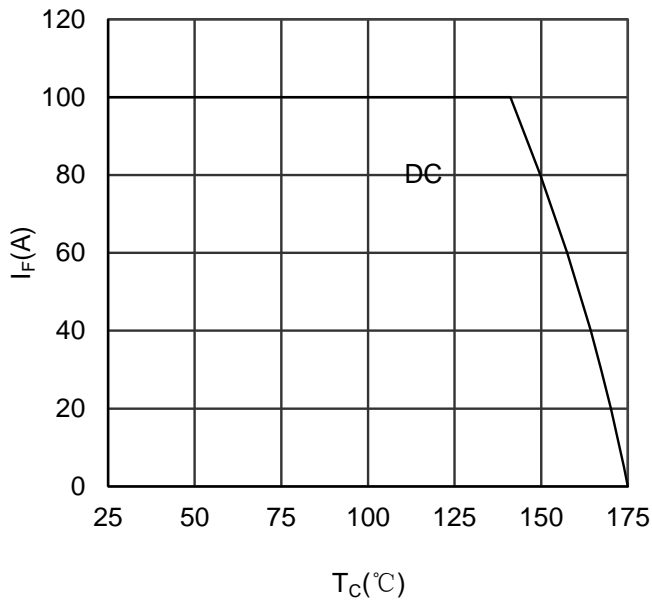


Figure 5. Forward current vs Case temperature

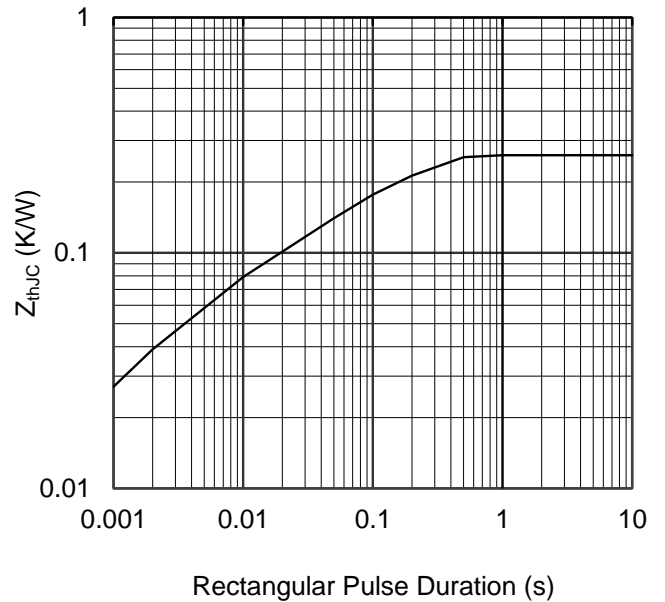


Figure 6. Transient Thermal Impedance

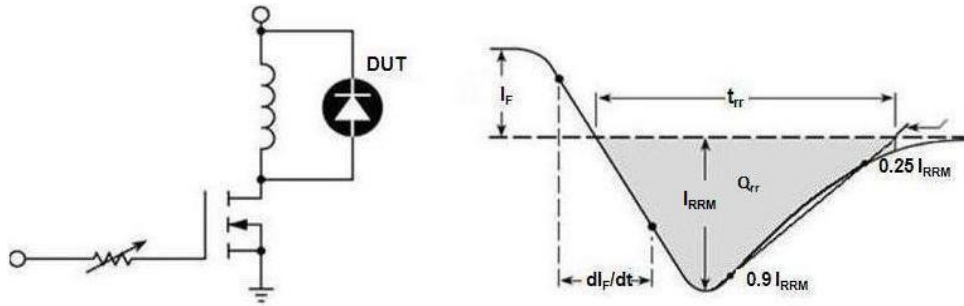
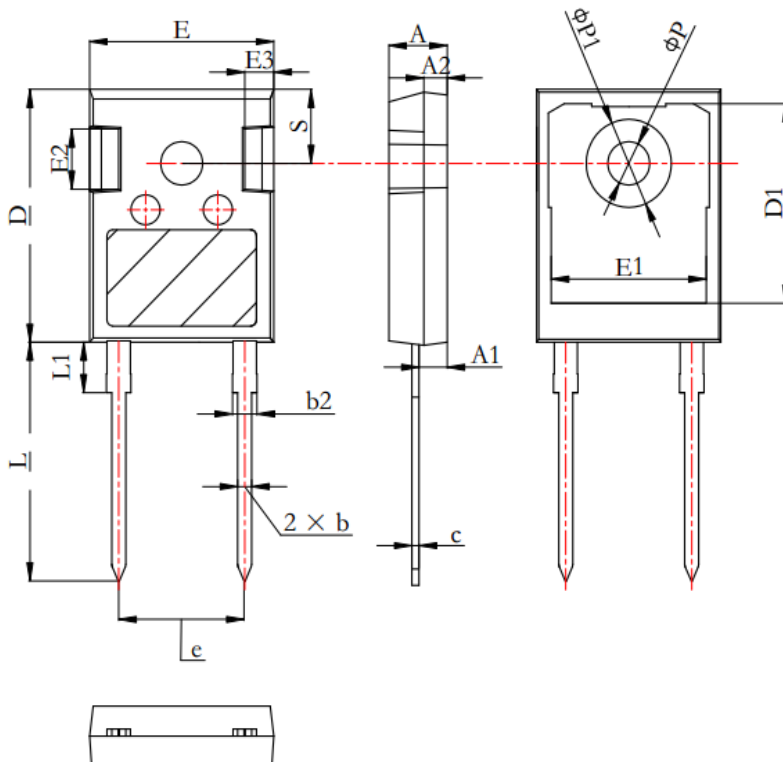


Figure 7. Diode Reverse Recovery Test Circuit and Waveform



Symbol	Min	Nom	Max
A	4.80	5.00	5.21
A1	2.21	2.41	2.61
A2	1.85	2.00	2.15
b	1.07	1.23	1.36
b2	1.90	2.05	2.30
c	0.50	0.60	0.75
e	10.88BSC		
E	15.50	15.80	16.13
E1	13.00	13.30	13.60
E2	3.68	5.00	5.20
E3	1.00	-	2.70
D	20.70	21.00	21.30
D1	16.25	16.55	16.85
L	19.60	19.91	20.22
L1	-	-	4.30
ΦP	3.40	3.60	3.80
ΦP1	-	-	7.30
S	6.15BSC		

Dimensions in (mm)

Figure 8. Package Outline